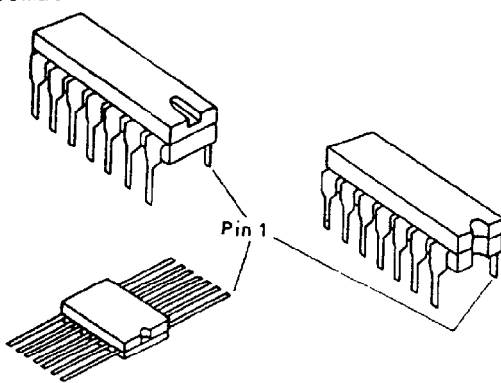


BRITISH STANDARDS INSTITUTION 2 PARK STREET, LONDON. W1A 2BS Specification available from:- AS SHOWN IN PD 9002 AND CECC 00 200 AND	BS CECC 90102 - 010 ISSUE 1 JANUARY 1982  Page 1 of 17 pages
ELECTRONIC COMPONENTS OF ASSESSED QUALITY DETAIL SPECIFICATION IN ACCORDANCE WITH: BS CECC 90 000 : 1976 BS CECC 90 100 : 1977	MANUFACTURERS TYPE NUMBER 54S132 64S132 74S132 84S132
Outline not to scale: Isometric projection Marking information see clause 1  Refer to IEC 191-1-50a (type A50B) Dual-in-Line (plastic or ceramic) refer to Appendix A1.3 Flatpack (metal or ceramic)	SEE PD 9002 AND CECC 00 200 For ordering information see clause 1 QUAD 2-INPUT POSITIVE NAND SCHMITT TRIGGER GATES TYPICAL CONSTRUCTION SILICON MONOLITHIC BIPOLAR CAVITY AND NON-CAVITY PACKAGES ASSESSMENT LEVELS R, S, T, AND V

1. Type description

1.1 Truth table (see page 2)

Refer to Qualified Products List PD 9002 and/or CECC 00 200
 for details of manufacturers approved to this specification

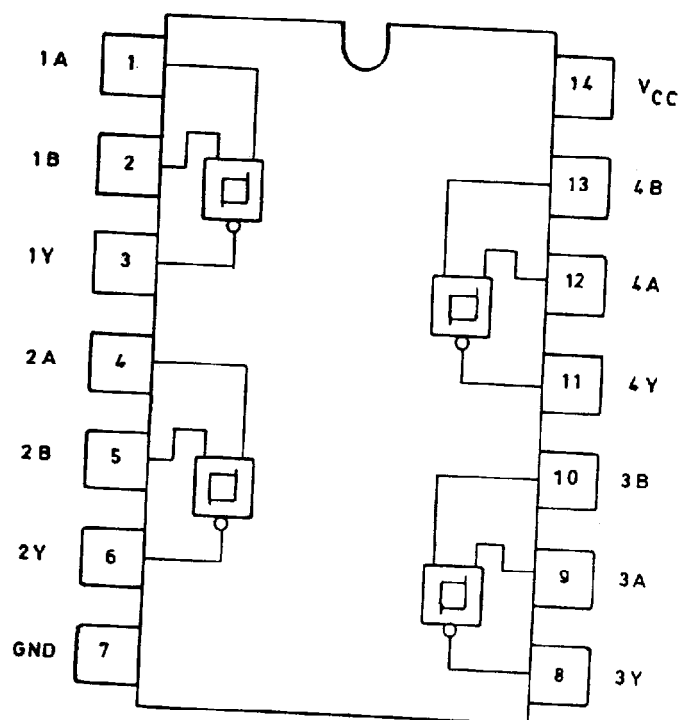
1.1 Truth table (contd)

INPUT		OUTPUT
A	B	Y
H	H	L
H	L	H
L	H	H
L	L	H

H = High level
L = Low level

1.2 Terminal identification, type designation and marking

1.2.1 Terminal identification



Quad 2-input positive nand schmitt trigger gates

1.2.2 Type designation

TEMPERATURE RANGE	PACKAGE		
	Ceramic Dual-in-Line	Plastic Dual-in-Line	Ceramic Flatpack
0 + 70	74S132J	N	W
-25 + 85	84S132J		
-40 + 85	64S132J		
-55 +125	54S132J		

1.2.3 Marking

Each integrated circuit shall bear the following markings:

- (1) Terminal identification
- (2) Type designation
- (3) Date code
- (4) Factory identification code (unless derived from trademark)
- (5) Manufacturers trade name or mark
- (6) Mark of conformity (unless a certificate of conformity is used)

1.3 Ordering information

Orders for these integrated circuits shall contain the following minimum information:

Manufacturers integrated circuit type designation, screening procedures and assessment levels as detailed to this CECC specification number.

(For details of screening procedures see Appendix A1.1)

2. Limiting conditions of use (not for inspection purposes)

2.1	Minimum and maximum continuous supply voltage	V_{CC}	-0,5V +7,0V
2.2	Minimum and maximum input voltages		
2.2.1	Minimum and maximum input voltage	V_I	-0,5V +5,5V
2.2.2	Maximum input voltage between multiple emitter transistor inputs	V_{II}	+5,5V

- 2.3 Minimum and maximum operating ambient temperatures $T_{amb}(^{\circ}\text{C})$ min. -55 -40 0 -25
max. +125 +85 +70 +85
- 2.4 Minimum and maximum storage temperatures $T_{stg}(^{\circ}\text{C})$ min. -65 (All types)
max. +150

3. Recommended operating conditions and associated characteristics (not for inspection purposes)

3.1 Recommended operating conditions.

These apply over the operating ambient temperature range unless otherwise stated.

Description	Symbol	Type	Value	Unit
Positive supply voltage range	V_{CC}	54S 64/74/84S	4,5 - 5,5 4,75 - 5,25	V V
Minimum value of High level input voltage	V_{IHB}	All types	2,0	V
Maximum value of High level input voltage	V_{IHA}	All types	5,5	V
Minimum value of negative going threshold voltage	$V_{T - B}$	All types	1,1	V
Maximum value of negative going threshold voltage	$V_{T - A}$	All types	1,4	V
Minimum value of positive going threshold voltage	$V_{T + B}$	All types	1,6	V
Maximum value of positive going threshold voltage	$V_{T + A}$	All types	1,9	V
Maximum value of Low level output current for each output	I_{OLA}	All types	20,0	mA
Maximum value of output current for each output at V_{OH}	I_{OHA}	All types	-1,0	mA
D.C. noise margin at Low level ($V_{ILA} - V_{OLA}$) at High level ($V_{OHB} - V_{IHB}$)	V_{NL} V_{NH}	All types 54S 64/74/84S	0,6 0,6 0,8	V V V

3.2 Associated characteristics

3.2.1 Minimum and maximum values are given for the worst case operation over the ambient temperature range, except for those conditions marked with an asterisk (*)

	54S	64S	74S	84S	
T _{amb} min.	-55	-40	0	-25	°C
T _{amb} max.	+125	+85	+70	+85	
V _{CC} min.	4,5	4,75			V
V _{CC} max.	5,5	5,25			

3.2.2

Characteristics	Conditions	$V_{CC}(\text{V})$	Symbol	Min.	Max.	Unit
Total supply current at High level	$V_{IL} = 0\text{V}^{(1)}$	$V_{CC} \text{ max.}$	I_{CCH}	-	44,0	mA
At Low level	$V_{IH} = 4,5\text{V}^{(1)}$	$V_{CC} \text{ max.}$	I_{CCL}	-	68,0	mA
High level input current	$V_{IH(1)} = 5,5\text{V}$	$V_{CC} \text{ max.}$	$I_{IH(1)}$	-	1,0	mA
	$V_{IH(2)} = 2,7\text{V}$	$V_{CC} \text{ max.}$	$I_{IH(2)}$	-	50,0	μA
Low level input current	$V_{IN} = 0,5\text{V}$	$V_{CC} \text{ max.}$	$-I_{IL}$	-	2,0	mA
Input clamping voltage	$-I_{IC} = 18,0\text{mA}$	$V_{CC} \text{ min.}$	$-V_{IC}$	-	1,2	V
Output voltage	54S $-I_{OH} = 1,0\text{mA}$	$V_{CC} \text{ min.}$	V_{OH}	2,5	-	V
	64/74/84S $-I_{OH} = 1,0\text{mA}$		V_{OH}	2,7	-	V
	All types $I_{OL} = 20,0\text{mA}^{(2)}$		V_{OL}	-	0,5	V
Output short circuit current	V_{IN} to give High level output $V_O = 0\text{V}^{(3)}$	$V_{CC} \text{ max.}$	$-I_{OS}$	40,0	100,0	mA

(1) To all inputs, (2) Fan out = 10

(3) Only one output at a time, duration $t \leq 1\text{s}$

*See Clauses 3.1 and 3.2.1 of this specification

3.2.2 (contd)

Characteristics	Conditions	$V_{CC}(V)$	Symbol	Min.	Max.	Unit
Propagation times All types	$T_{amb} = 25^{\circ}C^{*}$ test conditions as in Sub-group A5	5,0V				
High to Low level			t_{PHL}	-	13,0	ns
Low to High level			t_{PLH}	-	10,5	ns

*See Clauses 3.1 and 3.2.1 of this specification

3.3 Supplementary information

3.3.1 Change of typical propagation time with output loading

